Form PTO-1449 (Modified)	Atty Docket No.: P12759C	Serial No.: 10/618,226
List of Patents and Publications Statement (Use several sheets if necessary)		Applicant: Robert Chau et al.
		Filing Date: July 11, 2003

REFERENCE DESIGNATION — **U.S. PATENT DOCUMENTS**

Examiner Initials		Document No.		Class	Sub-Class	Filing date if appropriate
~	AA	6,121,094	Gardner et al.	438	287	
~	AB	6,436,777	Ota	438	305	
~	AC	6,514,828	Ahn et al.	438	297	
~	AD	6,617,209	Chau et al.	438	240	
~	AE	6,617,210	Chau et al.	438	240	
~	AF	US2002/0197790	Kizilyalli et al.	438	240	
~	AG	US2003/0045080	Visokay et al.	438	591	
	AH					
	AI					
	AJ					
	AK					
	AL					
	AM					
	AN					
	AO					
	AP					

FOREIGN PATENT DOCUMENTS

No.		Document No.	Date	Country	Class	Sub-Class	Translation
	AQ						
	AR						
	AS						
	AT						
	AU						

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

~	AV	Polishchuk et al., "Dual Workfunction CMOS Gate Technology Based on Metal Interdiffusion," ~~www.eecs.berkeley.edu~~, 1 page.
	AW	
	AX	
	AY	
	AZ	

Examiner [signature] Date Considered 4/15/04

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Substitute for Form 1449A/PTO (Modified)

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Complete if Known	
Application Number	10/618,226
Filing Date	July 11, 2003
First Named Inventor:	Robert Chau et al.
Group Art Unit	Unknown
Examiner Name	Unknown
Attorney Docket Number	P12759C

Sheet 1 of 1

U.S. PATENT DOCUMENTS

Exam. Initial*	Cite No.[1]	U.S. Patent Document Number	Kind Code[2] (If known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		6,184,072	B1	Kaushik et al.		
		6,420,279	B1	Ono et al.		
		6,544,906	B2	Rotondaro et al.		
		2003/0032303	A1	Yu et al.		

FOREIGN PATENT DOCUMENTS

Exam. Initial*	Cite No.[1]	Foreign Patent Document Office[3]	Number[4]	Kind Code[5] (If known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]

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[1]Unique citation designation number. [2]See attached Kinds of U.S. Patent Documents. [3]Enter Office that issued the document, by the two-letter code (WIPO Standard S.3). [4]For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. [5]Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. [6]Applicant is to place a check mark here if English language Translation is attached.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Complete if Known	
Application Number	~~Not yet assigned~~ 10/618,226
Filing Date	~~Herewith~~ 7/11/03
First Named Inventor:	Robert Chau et al.
Group Art Unit	~~Not yet assigned~~ 2813
Examiner Name	~~Not yet assigned~~ JACK CHEN
Attorney Docket Number	042390P12759C

Sheet	1	of	2

U.S. PATENT DOCUMENTS

Exam. Initial*	Cite No.[1]	U.S. Patent Document Number Code[2]	Kind (If known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
~		6,475,874	B2	Xiang et al.	11/5/2002	
~		6,063,698		Tseng et al.	5/16/2000	
~		5,753,560		Hong et al.	5/19/1998	
~		6,087,261		Nishikawa et al.	7/11/2000	
~		6,391,802	B1	Delpech et al.	5/21/2002	
~		5,783,478		Chau et al.	7/21/1998	
~		5,625,217		Chau et al.	4/29/1997	
~		6,306,742	B1	Doyle et al.	10/23/2001	
~		5,891,798		Doyle et al.	4/6/1999	

FOREIGN PATENT DOCUMENTS

Exam. Initial*	Cite No.[1]	Foreign Patent Document Office[3]	Number[4]	Kind Code[5] (If known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT *(use as many sheets as necessary)*				Application Number	~~Not yet assigned~~ 10/618,226
				Filing Date	~~Herewith~~ 7/11/03
				First Named Inventor:	Robert Chau et al.
				Group Art Unit	~~Not yet assigned~~ 2813
				Examiner Name	~~Not yet assigned~~ SACK CHEN
Sheet	2	**of**	2	Attorney Docket Number	042390P12759C

OTHER ART – NO PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T[2]
		Douglas Barlage et al., "High-Frequency Response of 100nm Integrated CMOS Transistor with High-K Gate Dieletrics", IEEE 2001	
		Robert Chau et al., "A 50nm Depleted-Substrate CMOS Transistor (DST), IEEE 2001	

Examiner Signature		Date Considered	4/15/04

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